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FQPF8N60CF N-Channel QFET[®] FRFET[®] MOSFET

600 V, 6.26 A, 1.5 Ω

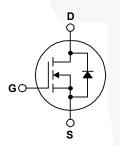
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

Features

- + 6.26 A, 600 V, R_{\rm DS(on)} = 1.5 Ω (Max.) @ V_{\rm GS} = 10 V, I_D = 3.13 A
- Low Gate Charge (Typ. 28 nC)
- Low Crss (Typ. 12 pF)
- 100% Avalanche Tested





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQPF8N60CFT	Unit	
V _{DSS}	Drain-Source Voltage		600	V	
I _D	Drain Current - Continuous ($T_C = 25^{\circ}C$)		6.26*	А	
	- Continuous (T _C = 100°C)		3.96*	А	
I _{DM}	Drain Current - Pulsed	(Note 1)	25*	A	
V _{GSS}	Gate-Source Voltage		± 30	V	
E _{AS}	Single Pulsed Avalanche Energy		160	mJ	
I _{AR}	Avalanche Current	(Note 1)	6.26	А	
E _{AR}	Repetitive Avalanche Energy		14.7	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5	V/ns	
P _D	Power Dissipation (T _C = 25°C)		48	W	
	- Derate above 25°C		0.38	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
Τ _L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	°C	

* Drain current limited by maximum junction temperature

Thermal Characteristics

Symbol	Parameter	FQPF8N60CFT	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	2.6	°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	°C/W	

FQPF8N
N60CF
N-Channel QFET®
QFET®
FRFET ®
MOSFET

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQPF8N60CFT	FQPF8N60CFT	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics T_C = 25°C unless otherwise noted.

Symbol	Parameter Test Conditions		Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	600			V
ΔBV_{DSS} / ΔT_J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu A$, Referenced to $25^{\circ}C$		0.7		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 600 V, V_{GS} = 0 V			10	μA
		V _{DS} = 480 V, T _C = 125°C			100	μA
I _{GSSF}	Gate-Body Leakage Current, Forward	V_{GS} = 30 V, V_{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V_{GS} = -30 V, V_{DS} = 0 V			-100	nA
On Charac	teristics				I.	
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$	2.0		4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 3.13 A		1.25	1.5	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 40 V, I _D = 3.13 A		8.7		S
Dynamic C	haracteristics					
C _{iss}	Input Capacitance	V_{DS} = 25 V, V_{GS} = 0 V,		965	1255	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		105	135	pF
C _{rss}	Reverse Transfer Capacitance			12	16	pF
Switching (Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = 300 V, I _D = 6.26A,		16.5	45	ns
t _r	Turn-On Rise Time	– R _G = 25 Ω		60.5	130	ns
t _{d(off)}	Turn-Off Delay Time			81	170	ns
t _f	Turn-Off Fall Time	(Note 4)		64.5	140	ns
Qg	Total Gate Charge	V _{DS} = 480 V, I _D = 6.26A,	-	28	36	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V		4.5		nC
Q _{gd}	Gate-Drain Charge	(Note 4)		12		nC
Drain-Sour	Lead to the construction of the constructio	3		I		
I _S Maximum Continuous Drain-Source Diode Forward Current					6.26	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				25	Α
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 6.26 A			1.4	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 6.26 A,		82		ns
Q _{rr}	Reverse Recovery Charge	dI _F / dt = 100 A/µs		242		nC

NOTES:

1. Repetitive rating : pulse-width limited by maximum junction temperature.

2. L = 7.3 mH, I_{AS} = 6.26 A, V_{DD} = 50 V, R_G = 25 Ω , starting T_J = 25°C.

3. I_{SD} \leq 6.26 A, di/dt \leq 200 A/ $\mu s,~V_{DD} \leq BV_{DSS,}$ Starting ~T_J = 25°C.

4. Essentially independent of operating temperature.

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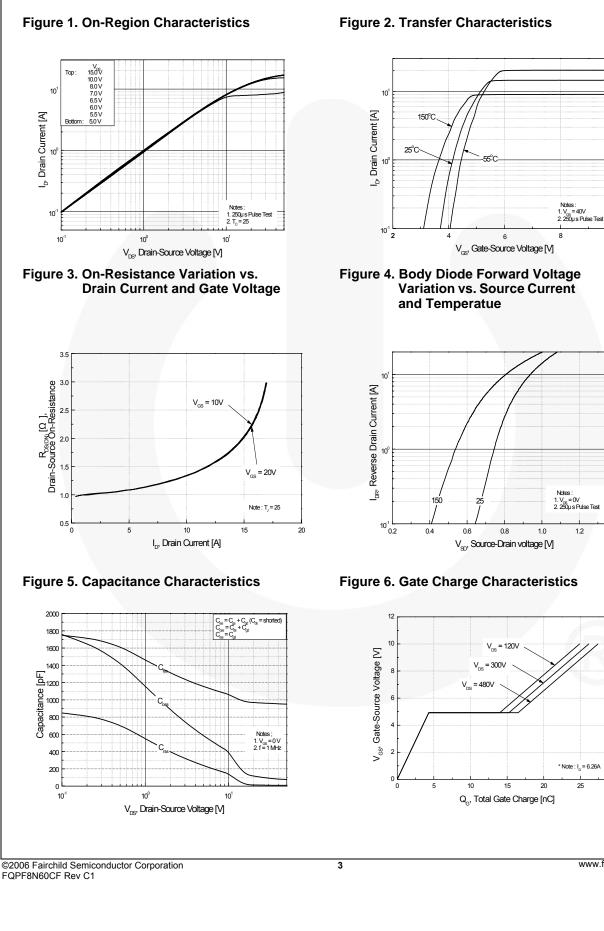
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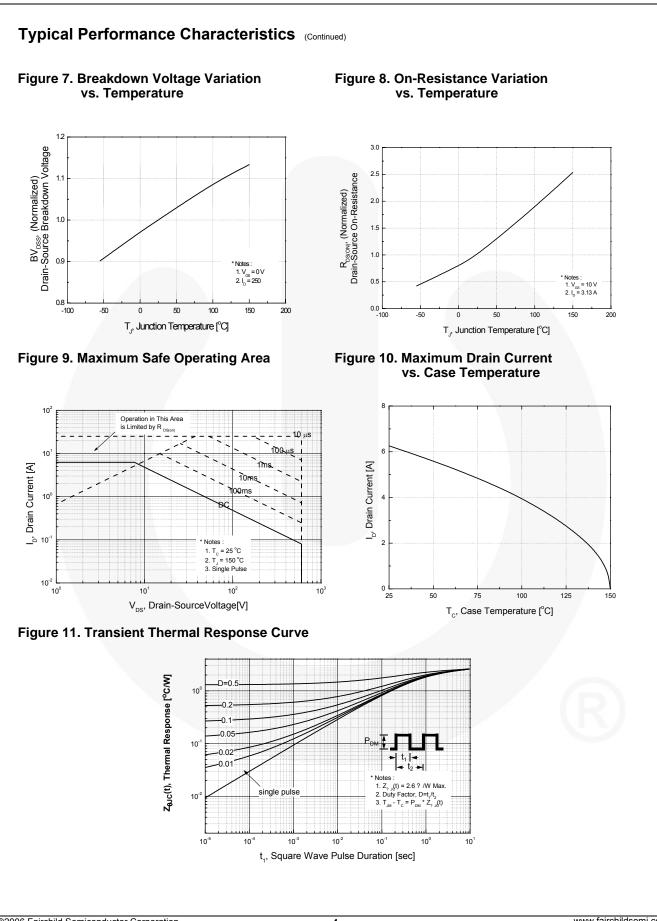
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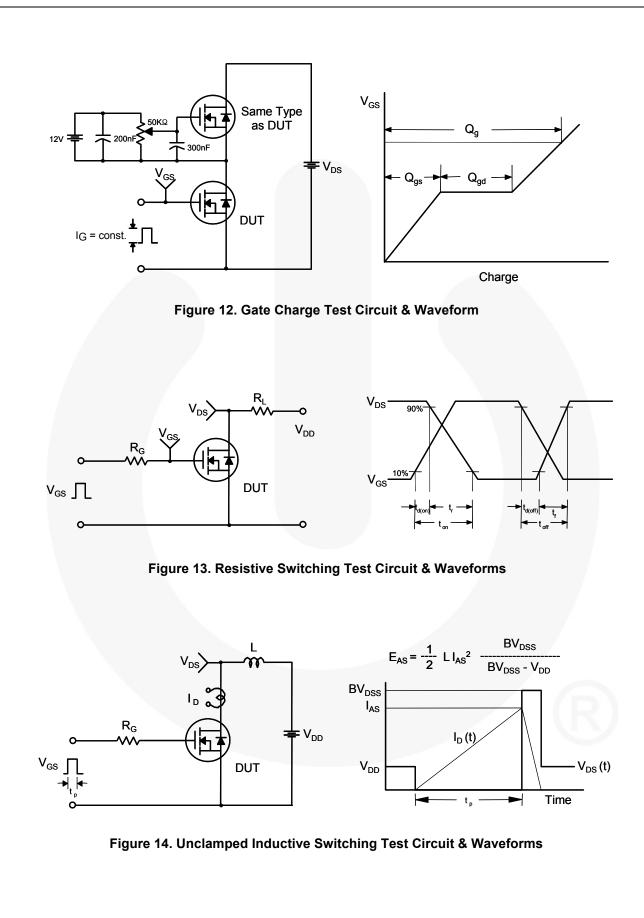


Typical Performance Characteristics

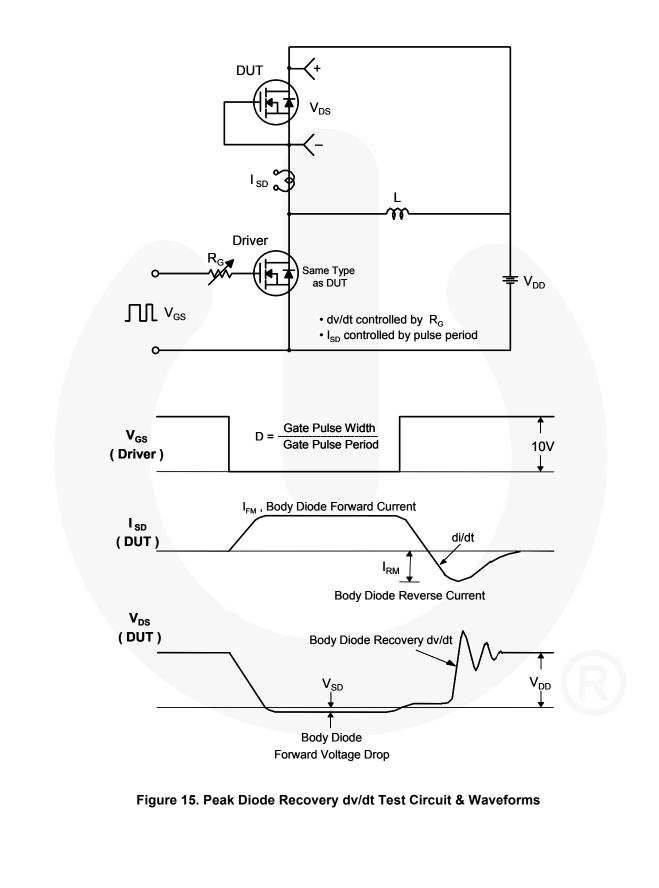


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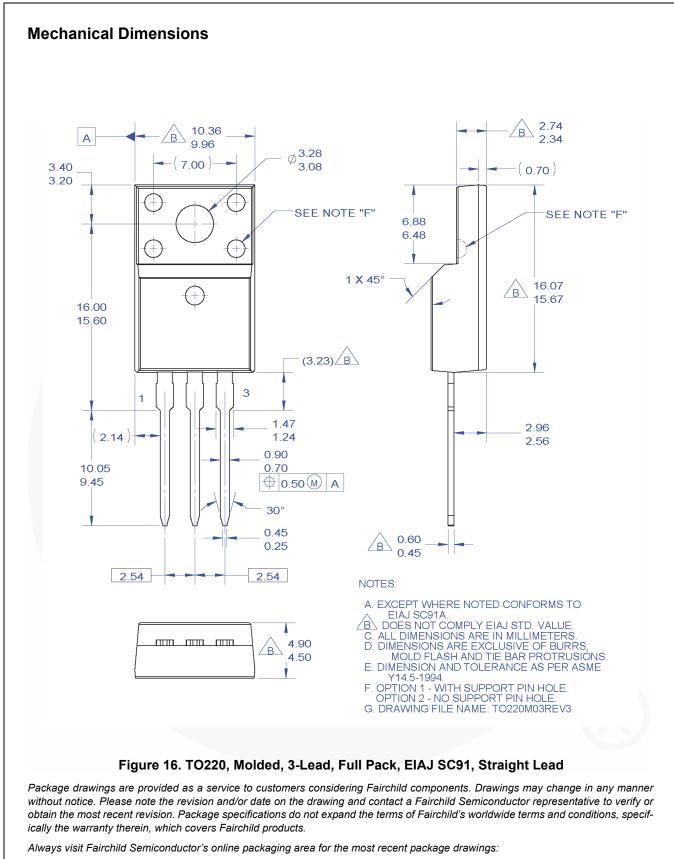


FQPF8N60CF — N-Channel QFET® FRFET® MOSFET



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